International Journal for Research in Engineering Application & Management (IJREAM)
ISSN : 2454-9150 Vol-10, Issue-04, July 2024

Novel Approaches in the Synthesis of Semiconductor Nanoclusters: A Comprehensive Review

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Abstract: Semiconductor nanoclusters, often referred to as quantum dots, have gained substantial attention due to their unique electronic and optical properties, which differ significantly from their bulk properties. This review aims to comprehensively cover recent advancements in the synthesis methods of semiconductor nanoclusters, highlighting innovative approaches that enhance their structural, electronic, and photonic properties. Key synthesis techniques, including chemical vapor deposition, molecular beam epitaxy, solvothermal methods and green synthesis routes are examined. The review also discusses the implications of these novel approaches in various applications such as photovoltaics, optoelectronics, and biomedical imaging.

Keywords : Synthesis, Semiconductor, Nanoclusters.

I. INTRODUCTION

The study of semiconductor nanoclusters began in earnest in the 1980 with the advent of advanced synthesis techniques and analytical tools capable of probing materials at the nanoscale [1]. Researchers observed that reducing the size of semiconductor crystals to the nanometer range resulted in significant changes in their physical properties, sparking widespread interest [2]. The concept of quantum confinement, where the motion of electrons and holes is restricted in all three spatial dimensions, became central to understanding these changes [3]. Luminescent nanoclusters have recently gained attention as new electrochemiluminescence (ECL) emitters due to their straightforward synthesis, low toxicity, ultrafine size, and remarkable photostability. Their use in the development of ECL emitters has been limited by their relatively low quantum yield in both aqueous and organic environments. [4]. In recent years, atomically precise metal nanoclusters have attracted significant research interest due to their remarkable properties. These properties, stemming from quantized electronic states, offer unique opportunities for creating nanomaterials with distinctive molecular-like absorption, luminescence, and magnetic characteristics. The study of monolayer-protected metal nanoclusters, particularly copper, featuring well-defined molecular structures and compositions, is a relatively new field, emerging only two to three decades ago [5].

Semiconductor nanoclusters also known as quantum dots are tiny particles that exhibit unique properties due to their size, typically in the range of 1 to 10 nanometers [3]. These nanoclusters bridge the gap between bulk materials and molecular structures, leading to quantum mechanical effects that are not present in larger particles. Due to their nanoscale dimensions, semiconductor nanoclusters possess a discrete energy spectrum, which profoundly influences their optical and electronic properties [6].

Semiconductor nanoclusters are of paramount importance in nanotechnology and materials science due to their size-dependent properties. These properties have been exploited in numerous applications, ranging from light emitting diodes and solar cells to medical diagnostics and quantum computing. The synthesis of semiconductor nanoclusters with precise control over size, shape and composition is crucial for tailoring their properties for specific applications [7].

II. TRADITIONAL SYNTHESIS METHODS

2.1 Chemical Vapor Deposition: Chemical vapour deposition involves the chemical reaction of gaseous precursors to form a solid material on a substrate. This method allows for precise control over the thickness and composition of the nanoclusters.

Basic Principles of Chemical Vapor Deposition: Precursor Preparation: The process begins with the selection of appropriate precursor gases. These gases contain the elements that will form the nanoclusters. Substrate Preparation: A substrate is prepared on which the nanoclusters will form. The choice of substrate can significantly influence the size, shape, and distribution of the nanoclusters. Reaction Chamber: The substrate is placed in a reaction chamber where the chemical vapor deposition process takes place. The chamber is typically maintained at low pressure. Reaction and flow of gas: Some gases are poured into the reaction chamber. The gases decompose or react on the hot substrate surface, leading to the formation of a solid material. The products of the reaction are usually

DOI : 10.35291/2454-9150.2024.0307

gaseous and are pumped out of the chamber. Nanocluster Formation: The solid material nucleates and grows on the substrate surface, forming nanoclusters. The conditions within the chamber, such as temperature, pressure, and gas flow rates, are critical in controlling the size and distribution of the nanoclusters [8].

In the thermal chemical vapor deposition the thermal energy to decompose precursor gases it is a common method for synthesizing metal and semiconductor nanoclusters. In the plasma enhanced chemical vapor deposition plasma is used to enhance chemical reactions at lower temperatures, this method is useful for substrates that cannot withstand high temperatures. Metal-Organic chemical vapor deposition involves metal-organic precursors and it is widely used for the deposition of compound semiconductors and for producing nanoclusters of materials like gallium arsenide and indium phosphide. Aerosol-Assisted chemical vapor deposition employs aerosol droplets containing the precursors and this method is advantageous for depositing materials with complex stoichiometries [8].

Nanoclusters of metals like platinum or palladium synthesized by chemical vapor deposition are used as catalysts in chemical reactions, fuel cells, and environmental applications. Semiconductor nanoclusters produced via chemical vapor deposition are used in electronics and optoelectronics such as transistors, solar cells, LEDs and quantum dot applications. Nanoclusters with high surface area-to-volume ratios are ideal for sensitive detection in gas sensors and biosensors. Nanoclusters of materials like lithium compounds are used as energy storage in battery electrodes to enhance performance [8].

2.2 Molecular beam epitaxy: Molecular beam epitaxy is a highly controlled and precise method used for the synthesis of semiconductor nanoclusters. This technique involves the deposition of atomic or molecular beams onto a substrate under ultra-high vacuum conditions allowing for the formation of high-purity and high quality nanostructures with atomic layer precision. MBE is widely used in the fabrication of various semiconductor materials including quantum dots, nanowires and thin films [9].

Molecular beam epitaxy operates under ultra high vacuum conditions, typically around 10^{-10} to 10^{-11} torr to minimize contamination and ensure high-quality growth. The process begins with the evaporation of source materials, such as metals or semiconductor compounds, from effusion cells or Knudsen cells. These cells are heated to specific temperatures to produce atomic or molecular beams that travel towards the substrate [10].

The key features of molecular beam epitaxy include the ultra high vacuum environment reduces the presence of impurities and allows for the precise control of deposition rates and composition. Effusion Cells are used to evaporate the source materials the temperature of each cell is carefully controlled to ensure a steady flux of atoms or molecules. The substrate temperature is controlled to optimize the adhesion and mobility of the incoming atoms promoting the formation of high-quality crystalline structures. In-Situ monitoring techniques such as reflection high-energy electron diffraction are used to monitor the growth process in real-time, providing feedback on the crystal quality and growth rate [11].

2.3 Solvothermal Methods: The solvothermal method is a widely used technique for synthesizing semiconductor nanoclusters due to its versatility and ability to produce high-quality materials with controlled morphology and composition. The solvothermal method involves dissolving precursors in a solvent and then heating the solution in a sealed vessel, typically an autoclave, at temperatures above the boiling point of the solvent. This creates high pressures that can promote the formation of nanoclusters. The solvent should dissolve the precursors and remain stable at high temperatures and pressures. Precursors are selected based on the desired composition of the nanoclusters. The mixture is heated to a temperature typically between 100°C and 300°C. Under high temperature and pressure, nucleation occurs followed by the growth of nanoclusters. The reaction mixture is cooled to room temperature, and the nanoclusters are collected and purified [12], [13].

III. NOVEL APPROACHES IN SYNTHESIS

3.1 Green Synthesis Routes: Green synthesis routes for semiconductor nanoclusters focus on using environmentally friendly and sustainable methods to reduce the environmental impact associated with traditional chemical synthesis. These methods often utilize non-toxic solvents, natural reducing agents, and energy-efficient processes. Reduced use of hazardous chemicals, lower energy consumption, minimization of waste and by-products, enhanced biocompatibility of synthesized nanoclusters are the benefits from the synthesis of novel approach [14], [15].

3.2 Microwave-Assisted Synthesis: Microwave-assisted synthesis is an effective method for the rapid and uniform heating of reaction mixtures which can significantly enhance the synthesis of semiconductor nanoclusters. This technique offers several advantages including reduced reaction times, improved yields and better control over particle size and distribution. Microwaves induce molecular rotation and ionic conduction which leads to rapid and uniform heating throughout the reaction mixture. This contrasts with conventional heating methods which often result in temperature gradients. Microwave-assisted synthesis is more energy efficient due to the direct interaction of microwaves with the reactants, leading to faster reaction rates and reduced energy consumption [16], [17].

DOI : 10.35291/2454-9150.2024.0307

3.3 Laser Ablation: The laser ablation method is a versatile and efficient technique for synthesizing semiconductor nanoclusters. This method involves using a high energy laser beam to ablate a target material in a liquid or gas environment leading to the formation of nanoclusters. In this high-energy laser beam is focused on a solid target material, the intense energy of the laser causes the material to vaporize and form a plasma plume. The method often produces nanoclusters with high purity as no chemical precursors or additives are involved. It is applicable to a wide range of materials, including metals, semiconductors, and ceramics. The size, morphology and composition of the nanoclusters can be finely tuned by adjusting the laser parameters and the ambient conditions [18], [19].

3.4 Electrochemical Synthesis: Electrochemical synthesis is a powerful and versatile method for producing semiconductor nanoclusters. This technique involves the use of an electrochemical cell where semiconductor materials are deposited or grown on an electrode surface from a solution containing the relevant ions. Electrochemical synthesis involves oxidation and reduction reactions at the electrode surfaces, these reactions lead to the deposition or formation of nanoclusters. Key parameters such as electrode potential, current density, electrolyte composition and temperature can be precisely controlled to influence the size, shape and composition of the nanoclusters [20], [21].

3.5 Template-Assisted Synthesis: Template-assisted synthesis is a versatile and widely used method for synthesizing semiconductor nanoclusters with well defined shapes and sizes. This technique involves using a template material that guides the formation of nanoclusters, ensuring uniformity and control over their morphology. A template material with a specific structure is used to guide the nucleation and growth of semiconductor nanoclusters, resulting in uniform and well-defined nanostructures. Templates can be hard such as porous anodic alumina, mesoporous silica or soft such as surfactants, block copolymers [22], [23].

IV. CHARACTERIZATION TECHNIQUES

To fully understand and utilize semiconductor nanoclusters, detailed characterization is essential. Techniques such as Transmission electron microscopy (TEM), Scanning electron microscopy (SEM), X-ray diffraction (XRD) and Photoluminescence Spectroscopy are commonly used to analyze the structural and optical properties of nanoclusters.

V. APPLICATIONS

Semiconductor nanoclusters can be engineered to absorb a broader spectrum of sunlight for improving the efficiency of solar cells. Quantum dot sensitized solar cells use semiconductor nanoclusters to increase the efficiency of converting solar energy into electricity. Quantum dots can be used in displays to provide purer colors, higher brightness and better energy efficiency compared to traditional light emitting diodes [24]. Quantum dots enhance the color performance and energy efficiency of liquid crystal display backlighting. Quantum dots provide stable and bright fluorescence, which is useful in bioimaging [25] for tracking and labeling cells and biomolecules. Nanoclusters can be used to develop highly sensitive biosensors for detecting biomolecules and pathogens.

VI. CHALLENGES AND FUTURE PERSPECTIVES

Despite their promising applications, the development and commercialization of semiconductor nanoclusters face several challenges. These include issues related to stability, toxicity, and the integration of nanoclusters into larger systems. Ongoing research aims to address these challenges by developing safer, more stable materials and improving synthesis and processing techniques.

The future of semiconductor nanoclusters looks promising, with potential breakthroughs in energy-efficient lighting, advanced medical diagnostics, and powerful quantum computers. As research progresses, the ability to precisely control and manipulate materials at the nanoscale will continue to unlock new technological advancements and improve existing applications.

VII. CONCLUSION

The synthesis of semiconductor nanoclusters has evolved significantly with the advent of novel approaches. These methods have opened new avenues for the development of advanced materials with tailored properties. Continued research and innovation in this field are essential for addressing current challenges and unlocking the full potential of semiconductor nanoclusters in various applications.

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